

MBR2035CT THRU MBR2060CT

20.0 AMPS. Schottky Barrier Rectifiers



Voltage Range 35 to 60 Volts Current 20.0 Amperes

TO-220

Features

- Plastic material used carries Underwriters Laboratory Classifications 94V-0
- Metal silicon junction, majority carrier conduction
- ♦ Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ♦ Guardring for overvoltage protection
- High temperature soldering guaranteed: 250°C/10 seconds,0.25"(6.35mm)from case

Mechanical Data

- ♦ Cases: JEDEC TO-220 molded plastic
- Terminals: Leads solderable per MIL-STD-750, Method 2026
- ♦ Polarity: As marked
- Mounting position: Any
- Mounting torque: 5 in. lbs. max
- Weight: 0.08 ounce, 2.24 grams

1185(4,70) 175(4,44)

Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

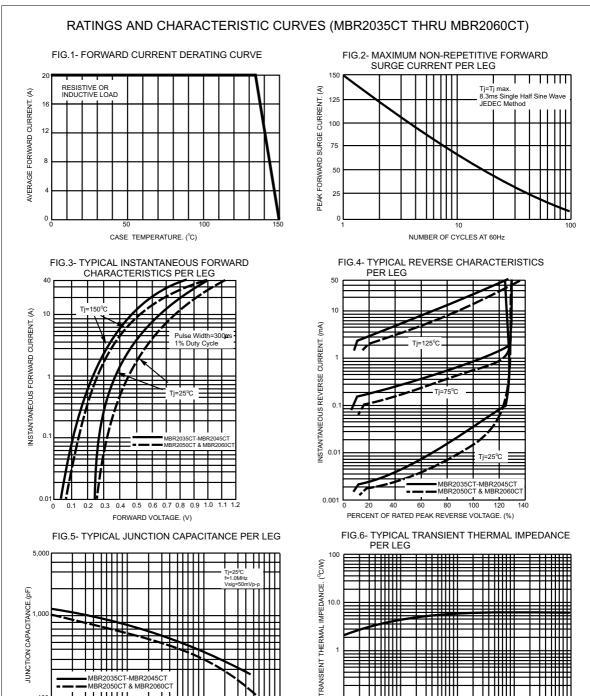
Type Number	MBR2035CT	MBR2045CT	MBR2050CT	MBR2060CT	Units
Maximum Recurrent Peak Reverse Voltage	35	45	50	60	V
Maximum RMS Voltage	24	31	35	42	V
Maximum DC Blocking Voltage	35	45	50	60	V
Maximum Average Forward Rectified Current at T_C =135°C	20				Α
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20KHz) at Tc=135°C	20.0			Α	
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	150			Α	
Peak Repetitive Reverse Surge Current (Note 1)	1.0		0.5		Α
Maximum Instantaneous Forward Voltage at (Note 2) =10A, Tc=25°C =10A, Tc=125°C =20A, Tc=25°C =20A, Tc=125°C	- 0.57 0.84 0.72		0.80 0.70 0.95 0.85		V
Maximum Instantaneous Reverse Current @ Tc=25°C at Rated DC Blocking Voltage @ Tc=125°C	0.1 15.0		0.15 150.0		mA mA
Voltage Rate of Change, (Rated V _R)	10,000				V/uS
Typical Thermal Resistance Per Leg (Note 3) RθJC	2.0				°C/W
Operating Junction Temperature Range T _J	-65 to +150			°C	
Storage Temperature Range TSTG	-65 to +175			°C	

Notes: 1. 2.0us Pulse Width, f=1.0 KHz

2. Pulse Test: 300us Pulse Width, 1% Duty Cycle

3. Thermal Resistance from Junction to Case Per Leg





0.01

10

T, PULSE DURATION. (sec)

100

■ MBR2035CT-MBR2045CT ■ MBR2050CT & MBR2060CT

REVERSE VOLTAGE. (V)

0.1